

PRECISION IN ELECTROCHEMISTRY



ZENNIUM X

THE ULTIMATE HIGH PERFORMANCE

Application Fields

Zahner potentiostats are designed as a modular concept, giving users the **freedom to customize** their potentiostat according to their needs. **High Power Applications**

Photoelectrochemistry / Photovoltaics

Electrochemistry

Addon Cards

Plug-and-play cards introduce additional input/control signals to the **ZENNIUM potentiostat.**

potentiostat



MIO

→ Additional analog & digital input/output channels for the ZENNIUM potentiostat

→ Allows process automatization via Thales scripting or remote integration

→ Analog channels provide 16-bit resolution at a range of ±10 V

TEMP/U

PAD4



65

→ For detailed stack characterization

→ Enable parallel measurement of each cell in a stacked system (batteries, fuel & electrolyzer cell stacks)

→ Simultaneous half-cell characterization for reference electrode setups

TEMP-U2

→ Two temperature recording channels

→ Two configurable input-voltage channels for recording data from external devices like a pH meter, pressure chamber, etc., during electrochemical measurements



Extensions For Power Applications

EPC42

Extend your **ZENNIUM potentiostat** for high quality impedance at high currents.

JJ EXTEND THE FUNCTIONALITY OF YOUR POTENTIOSTAT





RMUX

Extension For Medium Power Applications

- → Power potentiostats (PP) with power up to 200 W
- → Current up to ±40 A, voltage up to ±20 V
- → Remote integration possible via Python and C++



Extension For High Power Applications

- → Electronic load (EL) system with power up to 68 kW
- → Current up to ±680 A, voltage up to ±100 V
- → Remote integration possible via Python and C++

Main Specifications

- → EIS frequency range 10 µHz 12 MHz
- → 32-bit DC and 24-bit AC resolution
- → ±5 V / ±15 V voltage range
- → ±4 A over 12 current ranges
- → Online data processing for outstanding EIS



Slow CV scans with a scan rate of 10 $\mu\text{V/s}$ on a highly capacitive system with the ZENNIUM potentiostat (32-bit DAC resolution) and a conventional potentiostat (16-bit DAC resolution).



Single frequency (1 Hz), single period impedance measurements on a 25 $\mu\Omega$ resistor vs. time. The measurement is carried out with 1 A amplitude.

JJ THE HIGH-END POTENTIOSTAT

Our Strengths

We offer diverse extension possibilities for various electrochemical, photoelectrochemical/ photovoltaic applications.



CIMPS: Extend the potentiostat for use in the field of photoelectrochemistry/photovoltaics. The CIMPS system with its extensions support IMPS/IMVS, IPCE, spectroelectrochemistry measurements and many more.







amplitude time

IM-Sine: ZENNIUM potentiostats can carry out intelligent multi-sine EIS measurements, significantly decreasing the total measurement time.

For more information:



Accuracy Contour Plot

- \rightarrow Z > 0.1 Ω : potentiostatic mode, amplitude 10 mV
- Z > 1 MΩ: potentiostatic mode, amplitude 50 mV, shielded
- → Z < 0.1 Ω: galvanostatic mode, amplitude 100 mA

Ambient temperature / humidity +10 °C to +30 °C / < 60% without derating

- → Z < 0.01 Ω: galvanostatic mode, amplitude 1 A
- → Without DC bias voltage/current
- → Specified at the BNC terminals



Specifications

Potentiostatic modes

ADC resolution Function generator Harmonic reject Cell connection Ground reference

potentiostatic, galvanostatic, pseudo-galvanostatic, rest potential, ZRA, off
32 bit
digital and analog (ADF - for scan rates up to 10 kV/s)
> 60 dB @ 1/2 full scale
2-, 3-, 4-terminal kelvin
grounded, floating

Frequency generator & analyzer	Low range	High range
EIS frequency range	10 µHz to 12 MHz	
AC amplitude	0 to 2 V, 24 bit resolution	0 to 6 V, 24 bit resolution
Accuracy	< 0.0025%	
Resolution	0.0025%, 10,000 steps/decade	
Output potentiostatic	Low range	High range
Controlled voltage	±5 V	±15 V
Resolution	2.5 nV	7.5 nV
Accuracy	$\pm 50 \mu\text{V} \pm 5 \text{ppm of reading}$	$\pm 200 \mu\text{V} \pm 5 \text{ppm of reading}$
Compliance voltage	typ. 1 ppm, max. 2 ppm ±16 V	±32 V
Bandwidth	DC to 15 MHz @ 33 Ω load	-02 V
IR compensation	auto AC impedance technique, range 0 to 10 $M\Omega,$ resolution 0.012%	
Small signal rise time	150 ns to 200 μ s in 5 steps, automatic selection	
Slew rate	15 MV/s	
Phase shint	10° @ 500 kHz	
Output galvanostatic		
Controlled current	±4 A	
Current range	±1.9 nA to ±4 A in 12 current ranges	
Resolution	32 bit ± 0.2 ppb of FS	
Accuracy	$\pm 0.025\%$ of reading $\pm 0.01\%$ of FS, $\geq 1 \mu$ A to 100 mA $\pm 0.1\%$ of reading $\pm 0.05\%$ of FS, $\leq 1 \mu$ A or $> 100 m$ A	
la se set	Low range	High range
Input	Low range	підптапуе
Max. input voltage	±5.5 V	±16 V
Max. input voltage Voltage resolution	±5.5 V 2.5 nV	±16 V 7.5 nV
Max. input voltage Voltage resolution Voltage accuracy	$\pm 5.5 \text{ V}$ 2.5 nV $\pm 20 \text{ µV} \pm 2 \text{ ppm of reading}$	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy	±5.5 V 2.5 nV ±20 μ V ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μ A 100 mA	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
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Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy	town range ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 100 mA 4 A ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < $ 1 nA $ (HiZ-Probe) ± 10 The factor of the fa	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy	tow range ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 100 mA 4 A ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < $ 1 nA $ (HiZ-Probe) > 10 TΩ $ $ ±5 pF typ. (Main) / > 1000 TΩ $ $ ±1 pF typ. (HiZ-Probe) < ±200 fA typ < ±2 pA max / < ±10 fA typ. (HiZ-Probe)	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
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Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy	town range ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < $ 1 nA $ (HiZ-Probe) > 10 TΩ $ $ ±5 pF typ. (Main) / > 1000 TΩ $ $ ±1 pF typ. (HiZ-Probe) < ±200 fA typ., < ±2 pA max., / < ±10 fA typ. (HiZ-Probe) 1 mΩ to 10 GΩ / 1% (Main) 100 mΩ to 10 MΩ / 0.1%	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy Input impedance Input leakage current Impedance range	town range ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 100 mA 4 A ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < $ 1 nA $ (HiZ-Probe) > 10 TΩ $ $ ±5 pF typ. (Main) / > 1000 TΩ $ $ ±1 pF typ. (HiZ-Probe) < ±200 fA typ., < ±2 pA max., / < ±10 fA typ. (HiZ-Probe) 1 mΩ to 10 GΩ / 1% (Main) 100 mΩ to 10 MΩ / 0.1% 100 mΩ to 100 GΩ / 2% (HiZ-Probe)	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy Input impedance Input leakage current Impedance range	town range ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 100 mA 4 A ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < 1 nA (HiZ-Probe) > 10 TΩ ±5 pF typ. (Main) / > 1000 TΩ ±1 pF typ. (HiZ-Probe) < ±200 fA typ., < ±2 pA max., / < ±10 fA typ. (HiZ-Probe) 1 mΩ to 10 GΩ / 1% (Main) 100 mΩ to 10 MΩ / 0.1% 100 mΩ to 10 GΩ / 2% (HiZ-Probe) 10 μΩ to 1 GΩ / 2% (Gal)	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
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Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy Input impedance Input leakage current Impedance range	town range ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 10 mA 4 A ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < 1 nA (HiZ-Probe) > 10 TΩ ±5 pF typ. (Main) / > 1000 TΩ ±1 pF typ. (HiZ-Probe) < ±200 fA typ., < ±2 pA max., / < ±10 fA typ. (HiZ-Probe) 1 mΩ to 10 GΩ / 1% (Main) 100 mΩ to 10 MΩ / 0.1% 100 mΩ to 10 MΩ / 0.2% > 86 dB @ 10 μHz to 100 kHz > 66 dB @ 100 kHz to 12 MHz	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy Input impedance Input leakage current Impedance range Common mode rejection Input channel phase-tracking	towninge ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 10 mA 4 A ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < 1 nA (HiZ-Probe) > 10 TΩ ±5 pF typ. (Main) / > 1000 TΩ ±1 pF typ. (HiZ-Probe) < ±200 fA typ., < ±2 pA max., / < ±10 fA typ. (HiZ-Probe) 1 mΩ to 10 GΩ / 1% (Main) 100 mΩ to 100 GΩ / 2% (HiZ-Probe) 10 μΩ to 10 GΩ / 2% (Gal) 1 mΩ to 10 MΩ / 0.2% > 86 dB @ 10 μHz to 100 kHz > 66 dB @ 100 kHz to 12 MHz ±0.05° @ 10 μHz to 100 kHz	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
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Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy Input impedance Input leakage current Impedance range Common mode rejection Input channel phase-tracking acc. Equivalent effective input noise	town range ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < $ 1 nA $ (HiZ-Probe) > 10 TΩ $ $ ±5 pF typ. (Main) / > 1000 TΩ $ $ ±1 pF typ. (HiZ-Probe) < ±200 fA typ., < ±2 pA max., / < ±10 fA typ. (HiZ-Probe) 1 mΩ to 10 GΩ / 1% (Main) 100 mΩ to 10 MΩ / 0.1% 100 mΩ to 10 MΩ / 0.1% 100 mΩ to 10 MΩ / 0.2% > 86 dB @ 10 μHz to 100 kHz ≥ 66 dB @ 100 kHz to 12 MHz ±0.125° @ 100 kHz to 12 MHz ±0.125° @ 100 kHz to 12 MHz 1 μV rms / 100 fA rms @ 1 mHz to 10 Hz	±16 V 7.5 nV ±50 μV ± 5 ppm of reading
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Input Max. input voltage Voltage resolution Voltage accuracy DC current resolution DC current accuracy Input impedance Input leakage current Impedance range Common mode rejection Input channel phase-tracking acc. Equivalent effective input noise General PC interface Dimensions / Weight	towninge ±5.5 V 2.5 nV ±20 μV ± 2 ppm of reading 2 aA (32 bit) ±0.05% of reading ± 0.01% of FS @ 1 μA 100 mA ±0.5% of reading ± 0.1% of FS @ 10 nA 1 μA ±0.5% of reading ± 125 fA @ < 1 nA (HiZ-Probe) > 10 TΩ ±5 pF typ. (Main) / > 1000 TΩ ±1 pF typ. (HiZ-Probe) < ±200 fA typ., < ±2 pA max., / < ±10 fA typ. (HiZ-Probe) 1 mΩ to 10 GΩ / 1% (Main) 100 mΩ to 10 MΩ / 0.1% 100 mΩ to 100 GΩ / 2% (HiZ-Probe) 10 μΩ to 1 GΩ / 2% (Gal) 1 mΩ to 10 MΩ / 0.2% > 86 dB @ 10 μHz to 100 kHz > 66 dB @ 100 kHz to 12 MHz ±0.05° @ 100 μHz to 12 MHz ±0.125° @ 100 kHz to 12 MHz 1 μV rms / 100 fA rms @ 1 mHz to 10 Hz USB 2.0 160 × 470 × 376 mm ³ / 13.2 kg	±16 V 7.5 nV ±50 μV ± 5 ppm of reading

Zahner Analysis

EIS fitting

- → Create equivalent electrical circuits
- → Fit impedance spectra
- > Single fit > Series fit
- → ZHIT tool
- → Significance plot
- → Fitting accessible via API

Other techniques

- Cyclic voltammetry
 - > Peak determination > Charge integration
- Tafel slope measurements →
- → Butler-Volmer measurements
- → Analysis of photoelectrochemical measurements



Impedance spectrum (Bode plot) of a battery with the equivalent electrical circuit



Create your own equivalent electric circuit for EIS fitting



CV scans measured at different scan speeds



Impedance spectrum (Nyquist plot) with two time constants

ZHIT

The Zahner Analysis software features the unique ZHIT tool, which helps identifying artifacts in impedance spectra and allows reconstruction of artifact-free impedance spectra for fitting.

Significance Plot

Zahner Analysis software features an exclusive tool called the significance plot, which evaluates the frequency-dependent significance of equivalent circuit elements in the fitting.

Remote Integration Possible With:

→ Python→ C++

→ TCP/IP

JJ FROM REMOTE MEASUREMENT TO REMOTE DATA ANALYSIS **(**

Automate Your Electrochemistry

Integrate our potentiostats into your test bench for seamless operation. Zahner offers flexible remote control of the devices with ease. By integrating multiple potentiostats into a test bench, the user can create a high-quality multichannel system. Remote integration is possible via Python and C++.

Check different connection schemes:





Check out the QR code for useful examples and complete API documentation. Zahner-Elektrik GmbH & Co. KG contact@zahner.de www.zahner.de



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